imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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PHOTOTRANSISTOR

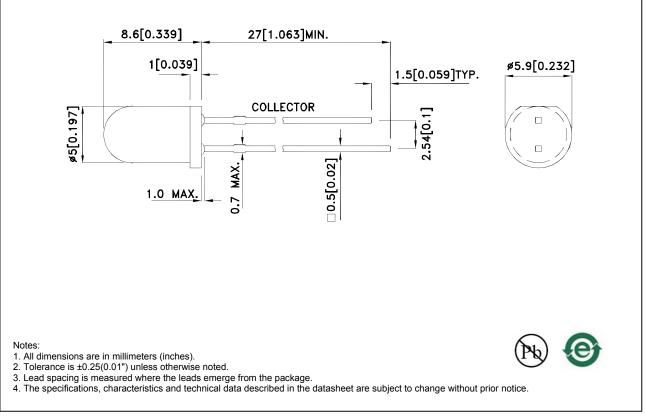
Part Number: WP7113P3BT

Features

- Mechanically and spectrally matched to the infrared emitting LED lamp .
- Blue transparent lens.
- RoHS compliant.

Description Made with NPN silicon phototransistor chips.

Package Dimensions



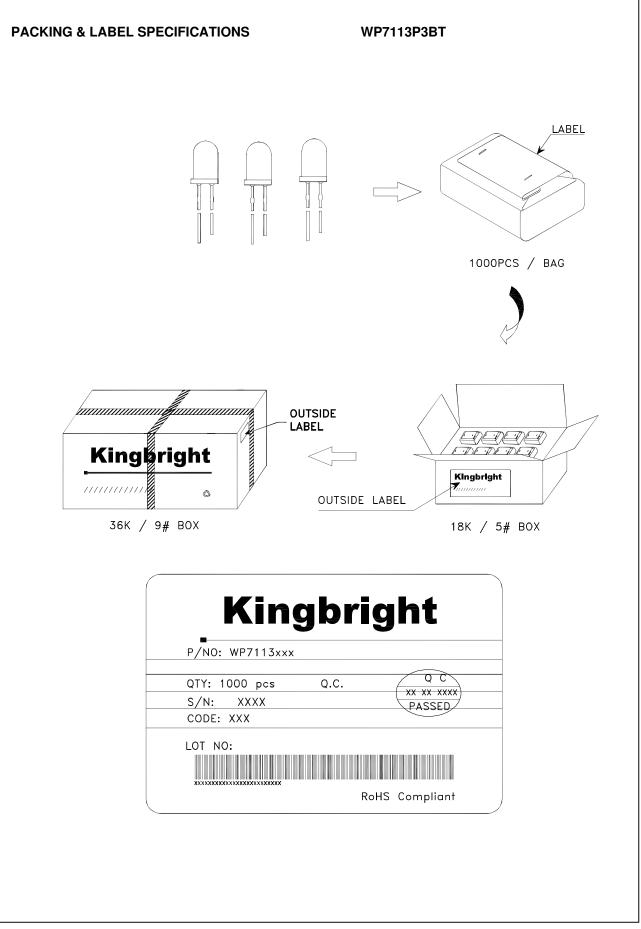
REV NO: V.4 CHECKED: Allen Liu DATE: FEB/07/2012 DRAWN: D.M.Su PAGE: 1 OF 5 ERP: 1101005146

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
VBR CEO	Collector-to-Emitter Breakdown Voltage	30			V	Ic=100uA Ee=0mW/c mឺ
VBR ECO	Emitter-to-Collector Breakdown Voltage	5			V	l∈=100uA Ee=0mW/c mঁ
VCE (SAT)	Collector-to-Emitter Saturation Voltage			0.8	v	Ic=2mA Ee=20mW/c mឺ
I CEO	Collector Dark Current			100	nA	VcE=10V Ee=0mW/c m ²
TR	Rise Time (10% to 90%)		15		us	Vce = 5V Ic=1mA RL=1000Ω
TF	Fall Time (90% to 10%)		15		us	
I (ON)	On State Collector Current	0.7	3		mA	VcE = 5V Ee=1mW/c m³ λ=940nm

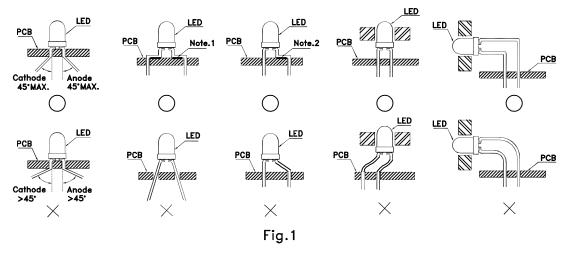
Absolute Maximum Ratings at TA=25°C

Parameter	Max.Ratings			
Collector-to-Emitter Voltage	30V			
Emitter-to-Collector Voltage	5V			
Power Dissipation at (or below) 25°C Free Air Temperature	100mW			
Operating Temperature	-40°C To +85°C			
Storage Temperature	-40°C To +85°C			
Lead Soldering Temperature (>5mm for 5sec)	260°C			

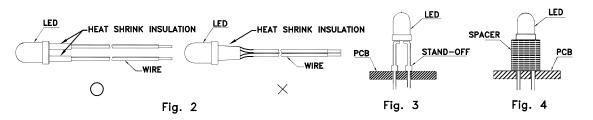


PRECAUTIONS

1. The lead pitch of the LED must match the pitch of the mounting holes on the PCB during component placement. Lead-forming may be required to insure the lead pitch matches the hole pitch. Refer to the figure below for proper lead forming procedures. (Fig. 1)



- \supset " Correct mounting method "imes " Incorrect mounting method
- 2. When soldering wire to the LED, use individual heat—shrink tubing to insulate the exposed leads to prevent accidental contact short—circuit. (Fig.2)
- 3.Use stand-offs (Fig.3) or spacers (Fig.4) to securely position the LED above the PCB.



- 4. Maintain a minimum of 2mm clearance between the base of the LED lens and the first lead bend. (Fig. 5 and 6)
- 5. During lead forming, use tools or jigs to hold the leads securely so that the bending force will not be transmitted to the LED lens and its internal structures. Do not perform lead forming once the component has been mounted onto the PCB. (Fig. 7)

